## (c) Amendments to the Claims

Please amend claims 1 and 2 as follows. A detailed listing of all the claims has been provided.

- 1. (Amended) An apparatus for forming a microcrystalline silicon series thin film on a substrate, having a portion in which said substrate is arranged to oppose to an electrode in a vacuum chamber, wherein said apparatus has a plurality of bar shaped electrodes as said electrode which are arranged such that they are perpendicular to a normal line of said substrate and their intervals to said substrate are all different or in part different and a high frequency power source for causing a said glow discharge using a high frequency power with an oscillation frequency in a range of from 50 MHz to 550 MHz whereby a glow.
- 2. (Currently Amended) An apparatus according to claim 1, wherein said plurality of bar shaped electrodes are arranged such that they are [[in]] parallel to each other.
- 3. (Original) An apparatus according to claim 1, wherein said plurality of bar shaped electrodes are arranged such that they are perpendicular to a transportation direction of the substrate.

- 4. (Original) An apparatus according to claim 1, wherein said plurality of bar shaped electrodes are arranged such that their intervals to the substrate are widened in an upper side of a transportation direction of the substrate and narrowed in a down side thereof.
- 5. (Original) An apparatus according to claim 1, wherein said plurality of bar shaped electrodes are arranged such that their intervals to the substrate are periodically changed to a transportation direction of the substrate.